NSN 5961-00-296-4124

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-296-4124 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Overall Diameter:** 1.281 inches **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Press fit **Semiconductor Material:** Germanium all semiconductor device diode Voltage Rating In Volts Per Characteristic: 4.0 forward voltage, dc all semiconductor device diode and 100.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 60.00 milliamperes source cutoff current all semiconductor device diode **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 1 electron tube base Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: